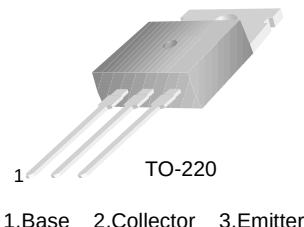


BDX53/A/B/C

Hammer Drivers, Audio Amplifiers Applications Power Liner and Switching Applications

- Power Darlington TR
- Complement to BDX54, BDX54A, BDX54B and BDX54C respectively



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage : BDX53	45	V
	: BDX53A	60	V
	: BDX53B	80	V
	: BDX53C	100	V
V_{CEO}	Collector-Emitter Voltage : BDX53	45	V
	: BDX53A	60	V
	: BDX53B	80	V
	: BDX53C	100	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current (DC)	8	A
I_{CP}	*Collector Current (Pulse)	12	A
I_B	Base Current	0.2	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	60	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage : BDX53	$I_C = 100\text{mA}, I_B = 0$	45			V
	: BDX53A		60			V
	: BDX53B		80			V
	: BDX53C		100			V
I_{CBO}	Collector Cut-off Current : BDX53	$V_{CB} = 45\text{V}, I_E = 0$			200	μA
	: BDX53A	$V_{CB} = 60\text{V}, I_E = 0$			200	μA
	: BDX53B	$V_{CB} = 80\text{V}, I_E = 0$			200	μA
	: BDX53C	$V_{CB} = 100\text{V}, I_E = 0$			200	μA
I_{CEO}	Collector Cut-off Current : BDX53	$V_{CE} = 22\text{V}, I_B = 0$			500	μA
	: BDX53A	$V_{CE} = 30\text{V}, I_B = 0$			500	μA
	: BDX53B	$V_{CE} = 40\text{V}, I_B = 0$			500	μA
	: BDX53C	$V_{CE} = 50\text{V}, I_B = 0$			500	μA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = 5\text{V}, I_C = 0$			2	mA
h_{FE}	* DC Current Gain	$V_{CE} = 3\text{V}, I_C = 3\text{A}$	750			
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 12\text{mA}$			2	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = 3\text{A}, I_B = 12\text{mA}$			2.5	V
V_F	* Parallel Diode Forward Voltage	$I_F = 3\text{A}$		1.8	2.5	V
		$I_F = 8\text{A}$		2.5		V

* Pulse Test: PW=300 μs , duty Cycle =1.5% Pulsed

Typical Characteristics

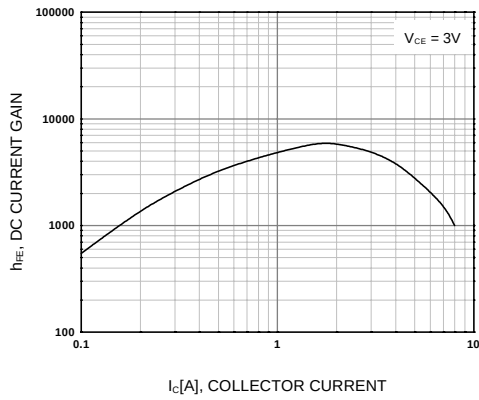


Figure 1. DC current Gain

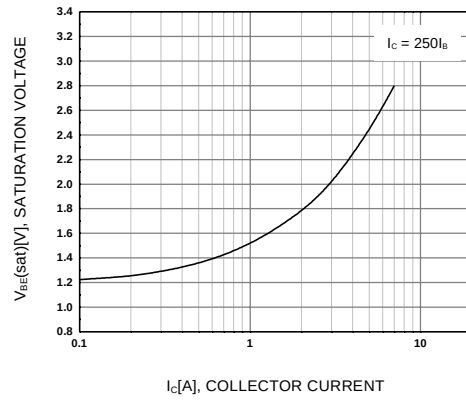


Figure 2. Base-Emitter Saturation Voltage

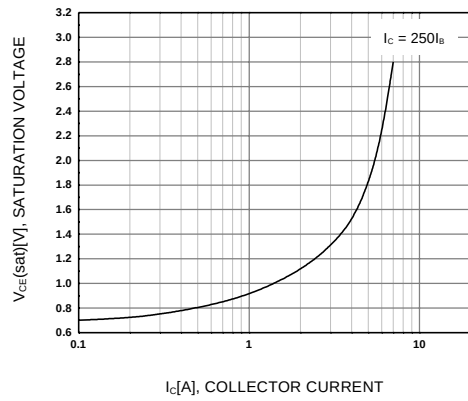


Figure 3. Collector-Emitter Saturation Voltage

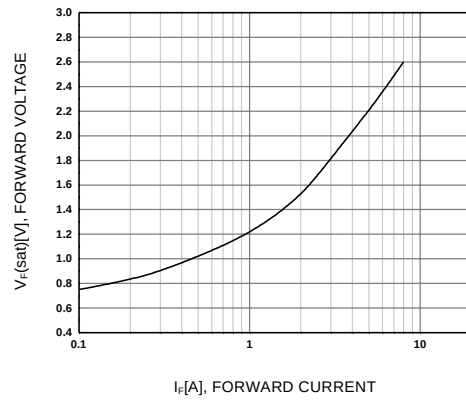


Figure 4. Damper Diode Forward Voltage

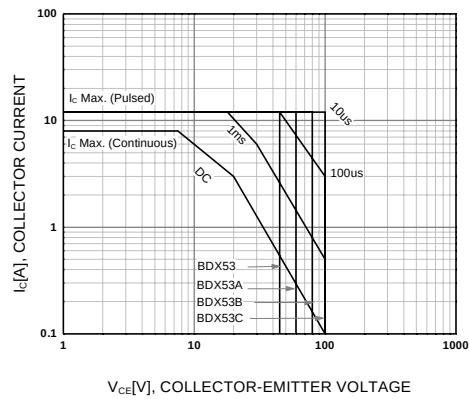


Figure 5. Safe Operating Area

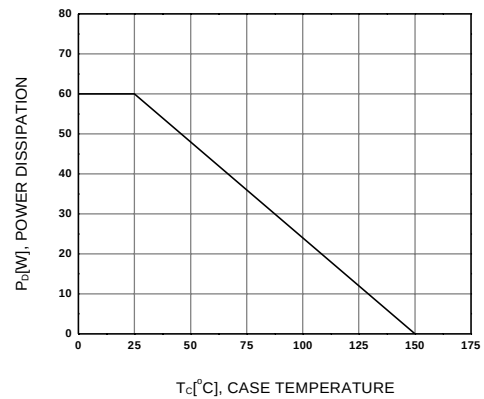


Figure 6. Power Derating

BDX53/A/B/C

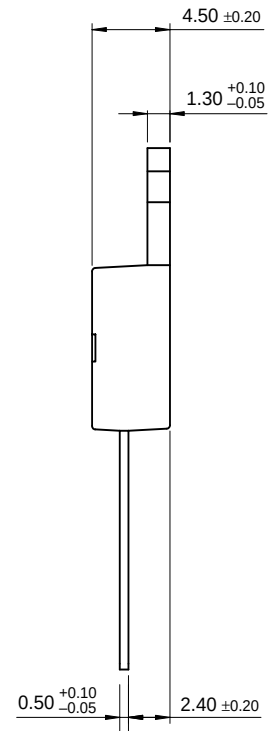
Technical drawing of a 3-pin connector, showing front and top views with dimensions in millimeters.

Front View Dimensions:

- Overall Width: 9.90 ± 0.20
- Overall Height: 18.95 MAX.
- Top Section Width: (8.70)
- Top Section Hole Diameter: $\varnothing 3.60 \pm 0.10$
- Top Section Height: 2.80 ± 0.10
- Central Section Height: (3.70)
- Bottom Section Height: 15.90 ± 0.20
- Pin Spacing (Left): 1.27 ± 0.10
- Pin Spacing (Right): 1.52 ± 0.10
- Pin Diameter: 0.80 ± 0.10
- Pin Length: 13.08 ± 0.20
- Pin Tip Radius: $R0.50$
- Pin Base Width: 2.54 TYP [2.54 ± 0.20]

Top View Dimensions:

- Overall Width: 10.00 ± 0.20



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